



High Voltage Resistors Series 400 MX Precision, Non-Inductive, Low TC

High Voltage Resistors Series 400 MX have been specifically developed for use in high performance industrial and laboratory high voltage systems. These precision high voltage resistors combine proprietary noninductive resistance system and design to achieve low temperature coefficient, low voltage coefficients, high stability and increased high operating voltages.

Low TC Precision High Voltage Resistors Series 400 MX are intended for use in low outgasing applications, SF6 and oil. Typical applications are medical systems like X-ray as well as power supplies or instruments.

Model	Wattage	Max. Oper.	Dimensions in millimeters ± 0.50 [Dimensions in inches ± 0.02]		
		Voltage	L	В	
MX400.2	3.80	15'000	27.00 [1.07]	8.00 [0.32]	
MX400.3	5.00	21'000	37.00 [1.46]	8.00 [0.32]	
MX400.5	7.50	30'000	52.00 [2.05]	8.00 [0.32]	
MX400.7	10.00	45'000	77.00 [3.03]	8.00 [0.32]	
MX400.10	13.50	60'000	102.00 [4.02]	8.00 [0.32]	
MX400.12	16.00	72'000	122.00 [4.80]	8.00 [0.32]	
MX400.15	20.00	90'000	152.00 [5.98]	8.00 [0.32]	



L±1

Characteristics

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Resistance Values	from 1K Ω to as high as 100G Ω on all models (to 1T Ω on request)				
Tolerances	0.05%, 0.1%, 0.25%, 0.5%, 1%, 2%, 5%, 10% (0.05% avail. to 10G, 0.25% to 100G, other on request)				
Temperature Coefficients	5, 10, 15, 25, 50 and 100 ppm/℃ (10 ppm/℃ available to 10G, 25 ppm/℃ to 100G, other on request)				
Operating Temperature	-55 +225 ℃ (extended temperature range to 350 ℃ available)				
Insulation Resistance	> 10'000 MΩ	500 Volt 25 ℃ 75% relative humidity			
Dielectric Strength	> 1'000 Volt	25 ℃ 75% relative humidity			
Thermal Shock	Δ R/R < 0.1% typ., 0.20% max.	MIL Std. 202, method 107 Cond. C IEC 68 -		IEC 68 - 2 -14	
Overload	Δ R/R < 0.1% typ., 0.25% max.	1,5 x Pnom, 5 sec (do not exceed max. voltage)			
Moisture Resistance	Δ R/R < 0.1% typ., 0.25% max.	MIL Std. 202, method 106 IEC 68 - 2 -		IEC 68 - 2 - 3	
Load Life	Δ R/R < 0.1% typ., 0.25% max.	1000 hours at rated power IE		IEC 115 - 1	
Encapsulation	Screen Printed Silicone	Core Material Al ₂ O ₃ (96%)		%)	
Lead Material	Gold Plated	Resistor Material Ruthenium Oxide		m Oxide	

Voltage Coefficients of Resistance

Model	Resistance Range	VCR (-ppm/V)*
MX400.2	1K 500M 500M 5G	< 0.40 < 0.75
MX400.3	1K 1G 1G 10G	< 0.20 < 0.40
MX400.5	1K 1G5 1G5 15G	< 0.15 < 0.30
MX400.7	1K 2G5 2G5 25G	< 0.10 < 0.15
MX400.10	1K 3G 3G30G	< 0.08 < 0.12
MX400.12	1K 4G 4G 40G	< 0.06 < 0.10
MX400.15	1K 5G 5G 50G	< 0.04 < 0.08

Derating Curve

35±2



* typical values, contact factory for details